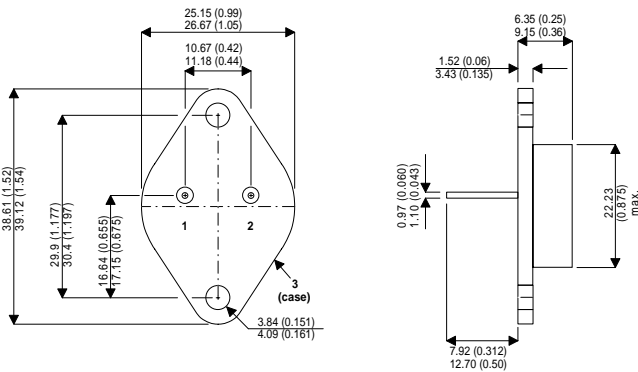


**HIGH CURRENT
HIGH SPEED
HIGH POWER TRANSISTOR**

MECHANICAL DATA

Dimensions in mm(inches)



DESCRIPTION

The BUX20 is a silicon multi-epitaxial planar NPN transistor in modified Jedec TO-3 metal case, intended for use in switching and linear applications in military and industrial equipment.

TO-3 PACKAGE (TO-204AA)

PIN 1 — Base PIN 2 — Emitter Case is Collector.

ABSOLUTE MAXIMUM RATINGS ($T_{case} = 25^{\circ}C$ unless otherwise stated)

V_{CBO}	Collector – Base Voltage ($I_E = 0$)	160V
V_{CEX}	Collector – Emitter Voltage ($V_{BE} = -1.5V$)	160V
V_{CEO}	Collector – Emitter Voltage ($I_B = 0$)	125V
V_{EBO}	Emitter – Base Voltage ($I_C = 0$)	7V
I_C	Collector Current	50A
I_{CM}	Collector Peak Current ($t_p = 10$ ms)	60A
I_B	Base Current	10A
P_{tot}	Total Power Dissipation at $T_{case} \leq 25^{\circ}C$	350W
T_{stg}	Storage Temperature	-65 to 200°C
T_J	Junction Temperature	200°C

Semelab Plc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

ELECTRICAL CHARACTERISTICS ($T_{case} = 25^{\circ}C$ unless otherwise stated)

Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$V_{CEO(sus)^*}$	Collector - Emitter Sustaining Voltage $I_C = 200mA$	125			V
V_{EBO}	Emitter – Base Voltage $I_E = 50mA$ $I_C = 0$	7			V
I_{CEO}	Collector Cut-off Current $V_{CE} = 100V$ $I_B = 0$			3	mA
I_{CEX}	Collector Cut-off Current $V_{CE} = 160V$ $V_{BE} = -1.5V$ $T_C = 125^{\circ}C$			3	mA
				12	
I_{EBO}	Emitter Cut-off Current $I_C = 0$ $V_{EB} = 5V$			1	mA
$V_{CE(sat)^*}$	Collector – Emitter Saturation Voltage $I_C = 25A$ $I_B = 2.5A$		0.3	0.6	V
	$I_C = 50A$ $I_B = 5A$		0.55	1.2	
$V_{BE(sat)^*}$	Base – Emitter Saturation Voltage $I_C = 50A$ $I_B = 5A$		1.35	2	V
h_{FE}^*	DC Current Gain $I_C = 25A$ $V_{CE} = 2V$	20		60	—
	$I_C = 50A$ $V_{CE} = 4V$	10			
$I_{S/b}$	Second Breakdown Collector Current $V_{CE} = 40V$ $t = 1s$	0.15			A
	$V_{CE} = 20V$ $t = 1s$	17.5			
f_T	Transition Frequency $I_C = 2A$ $V_{CE} = 15V$ $f = 10MHz$	8			MHz
t_{on}	Turn-On Time $I_C = 50A$ $I_{B1} = 5A$ $V_{CC} = 60V$		0.4	1.5	μs
t_s	Storage Time $I_C = 50A$ $I_{B1} = 5A$		0.85	1.2	
t_f	Fall Time $I_{B2} = -5A$ $V_{CC} = 60V$		0.1	0.3	

* Pulsed: pulse duration = 300ms, duty cycle $\leq 2\%$

THERMAL CHARACTERISTICS

$R_{\theta JC}$	Thermal Resistance Junction to Case	0.5		$^{\circ}C/W$
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Part number search for devices beginning "BUX20"

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Datasheets are downloaded as Acrobat PDF files.



Bipolar Products

PRODUCT	Polarity	Package	V _{CEO}	I _{C(cont)}	H _{FE(min)}	H _{FE(max)}	@ V _{CE} /I _C	F _T	P _D
BUX20	NPN	TO3	125V	50A	20	60	2/25	8MHz	350W
BUX20CECC	NPN	TO3	125V	50A	20	60	2/25	8MHz	350W
BUX20-JQR-B	NPN	TO3	125V	50A	20	60	2/25	8MHz	350W

Searched through 3083 records and found 3 products matching your criteria.

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